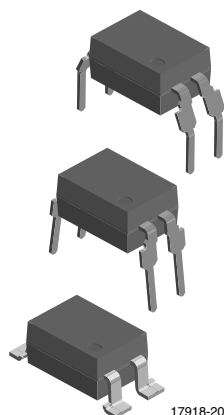
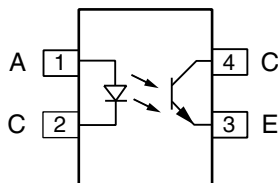


Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}, 110 °C Rated



17918-20



FEATURES

- Operating temperature from -55 °C to +110 °C
- Good CTR linearity depending on forward current
- Isolation test voltage, 5300 V_{RMS}
- High collector emitter voltage, V_{CEO} = 70 V
- Low saturation voltage
- Fast switching times
- Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

DESCRIPTION

The 110 °C rated SFH617A (DIP) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6.

APPLICATIONS

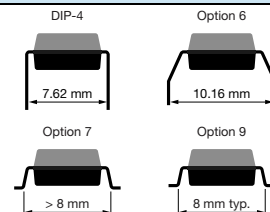
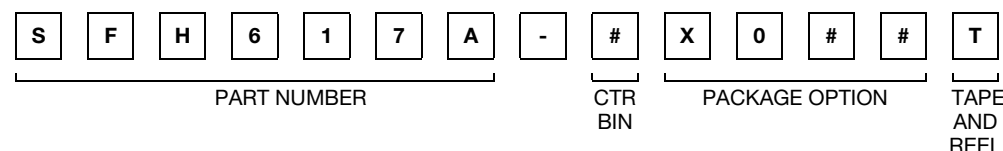
- AC adapter
- SMPS
- PLC
- Factory automation
- Game consoles

AGENCY APPROVALS

The safety application model number covering all products in this datasheet is SFH617A. This model number should be used when consulting safety agency documents.

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO
- CQC

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)			
UL, BSI, FIMKO, cUL	40 to 80	63 to 125	100 to 200	160 to 320
DIP-4	SFH617A-1	SFH617A-2	SFH617A-3	SFH617A-4
DIP-4, 400 mil, option 6	SFH617A-1X006	SFH617A-2X006	SFH617A-3X006	SFH617A-4X006
SMD-4, option 7	SFH617A-1X007T	-	SFH617A-3X007T	-
SMD-4, option 9	-	SFH617A-2X009T	-	-
VDE, UL, BSI, FIMKO, cUL	40 to 80	63 to 125	100 to 200	160 to 320
DIP-4	SFH617A-1X001	SFH617A-2X001	SFH617A-3X001	SFH617A-4X001
DIP-4, 400 mil, option 6	SFH617A-1X016	SFH617A-2X016	SFH617A-3X016	SFH617A-4X016
SMD-4, option 7	-	SFH617A-2X017T	SFH617A-3X017T ⁽¹⁾	-
SMD-4, option 9	-	SFH617A-2X019T ⁽¹⁾	-	-

Notes

- Additional options may be possible, please contact sales office.

⁽¹⁾ Also available in tubes; do not add T to end.



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \leq 10\text{ }\mu\text{s}$	I_{FSM}	2.5	A
LED power dissipation	at $25\text{ }^{\circ}\text{C}$	P_{diss}	70	mW
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5$, $t_p \leq 10\text{ ms}$	I_{CM}	100	mA
Output power dissipation	at $25\text{ }^{\circ}\text{C}$	P_{diss}	150	mW
COUPLER				
Operation temperature		T_{amb}	- 55 to + 110	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	2 mm from case, $\leq 10\text{ s}$	T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 60 mA		V _F		1.35	1.65	V
Reverse current	V _R = 6 V		I _R		0.01	10	μA
Capacitance	V _R = 0 V, f = 1 MHz		C _O		13		pF
OUTPUT							
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz		C _{CE}		5.2		pF
Collector emitter leakage current	V _{CE} = 10 V	SFH617A-1	I _{CEO}		2	50	nA
		SFH617A-2	I _{CEO}		2	50	nA
		SFH617A-3	I _{CEO}		5	100	nA
		SFH617A-4	I _{CEO}		5	100	nA
COUPLER							
Collector emitter saturation voltage	I _F = 10 mA, f = 1 MHz		V _{CEsat}		0.25	0.4	V
Coupling capacitance			C _C		0.4		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

**CURRENT TRANSFER RATIO** ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$I_F = 10\text{ mA}$, $V_{CE} = 5\text{ V}$	SFH617A-1	CTR	40		80	%
		SFH617A-2	CTR	63		125	%
		SFH617A-3	CTR	100		200	%
		SFH617A-4	CTR	160		320	%
	$I_F = 1\text{ mA}$, $V_{CE} = 5\text{ V}$	SFH617A-1	CTR	13	30		%
		SFH617A-2	CTR	22	45		%
		SFH617A-3	CTR	34	70		%
		SFH617A-4	CTR	56	90		%

SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Turn-on time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_{on}		3		μs
Rise time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_r		2		μs
Turn-off time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_{off}		2.3		μs
Fall time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_f		2		μs
Cut-off frequency	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$		f_{CO}		100		kHz
SATURATED							
Turn-on time	$I_F = 20\text{ mA}$	SFH617A-1	t_{on}		3		μs
	$I_F = 10\text{ mA}$	SFH617A-2	t_{on}		4.2		μs
		SFH617A-3	t_{on}		4.2		μs
	$I_F = 5\text{ mA}$	SFH617A-4	t_{on}		6		μs
Rise time	$I_F = 20\text{ mA}$	SFH617A-1	t_r		2		μs
	$I_F = 10\text{ mA}$	SFH617A-2	t_r		3		μs
		SFH617A-3	t_r		3		μs
	$I_F = 5\text{ mA}$	SFH617A-4	t_r		4.6		μs
Turn-off time	$I_F = 20\text{ mA}$	SFH617A-1	t_{off}		18		μs
	$I_F = 10\text{ mA}$	SFH617A-2	t_{off}		23		μs
		SFH617A-3	t_{off}		23		μs
	$I_F = 5\text{ mA}$	SFH617A-4	t_{off}		25		μs
Fall time	$I_F = 20\text{ mA}$	SFH617A-1	t_f		11		μs
	$I_F = 10\text{ mA}$	SFH617A-2	t_f		14		μs
		SFH617A-3	t_f		14		μs
	$I_F = 5\text{ mA}$	SFH617A-4	t_f		15		μs

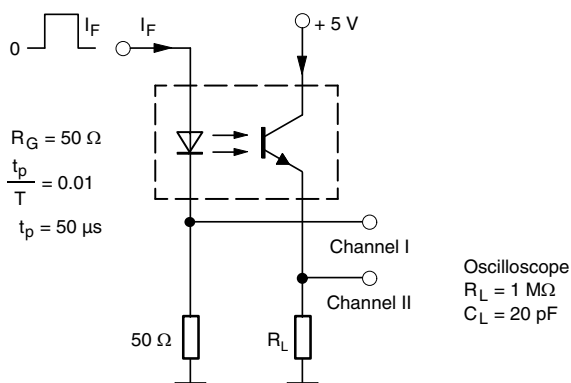


Fig. 1 - Test Circuit, Non-Saturated Operation

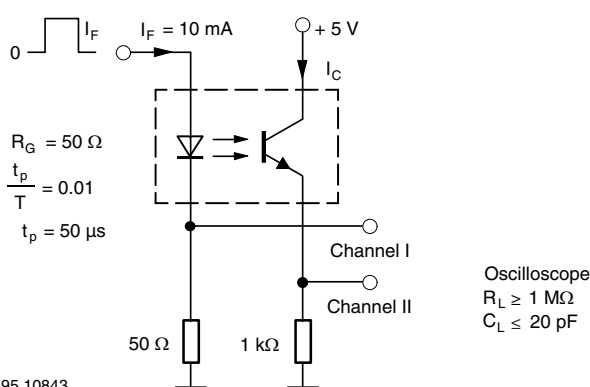


Fig. 2 - Test Circuit, Saturated Operation

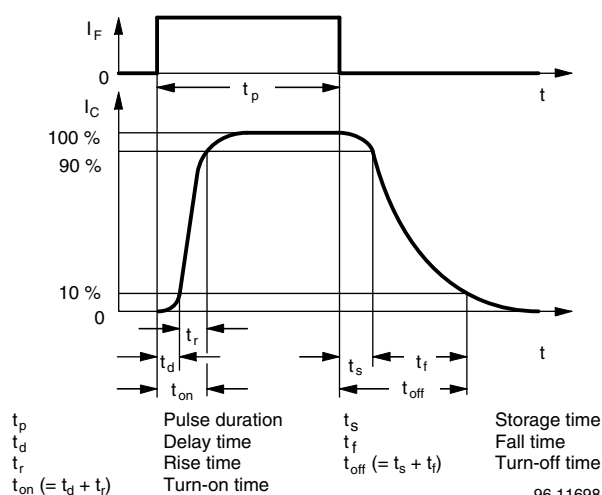


Fig. 3 - Switching Times

SAFETY AND INSULATION RATINGS

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55/115/21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	4470	V _{RMS}
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V _{ISO}	5300	V _{RMS}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V _{IOTM}	8000	V _{peak}
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	890	V _{peak}
Isolation resistance	T _{amb} = 25 °C, V _{IO} = 500 V	R _{IO}	≥ 10 ¹²	Ω
	T _{amb} = 100 °C, V _{IO} = 500 V	R _{IO}	≥ 10 ¹¹	Ω
Output safety power		P _{SO}	700	mW
Input safety current		I _{SI}	400	mA
Input safety temperature		T _S	175	°C
Creepage distance	DIP-4		≥ 7	mm
Clearance distance	DIP-4		≥ 7	mm
Creepage distance	DIP-4, 400 mil, option 6		≥ 8	mm
Clearance distance	DIP-4, 400 mil, option 6		≥ 8	mm
Creepage distance	SMD-4, option 7 and option 9		≥ 7	mm
Clearance distance	SMD-4, option 7 and option 9		≥ 7	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

- As per DIN EN 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

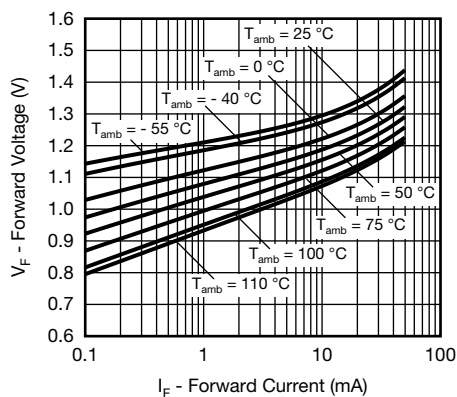
TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


Fig. 4 - Forward Voltage vs. Forward Current

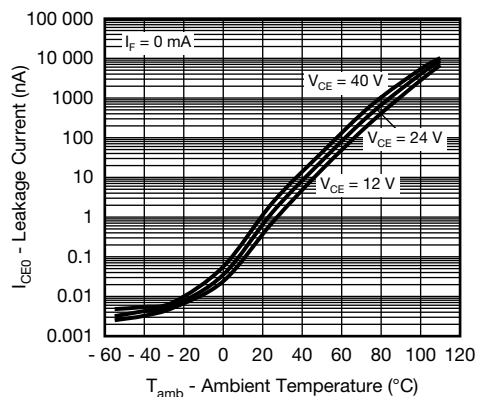


Fig. 7 - Leakage Current vs. Ambient Temperature

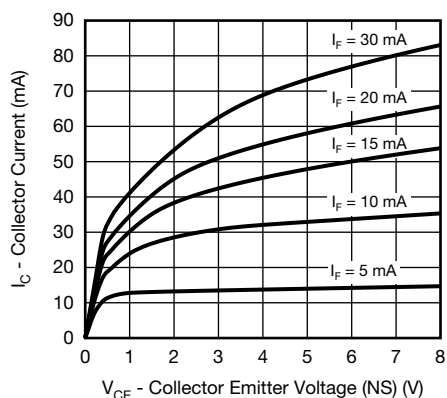


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

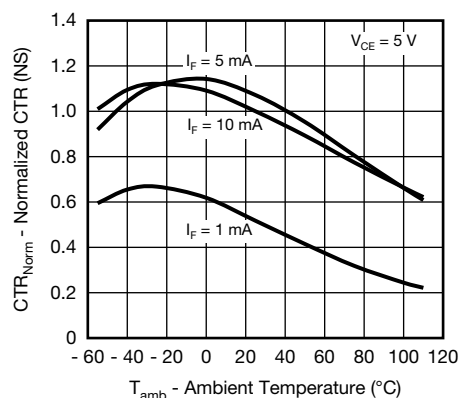


Fig. 8 - Normalized CTR (NS) vs. Ambient Temperature

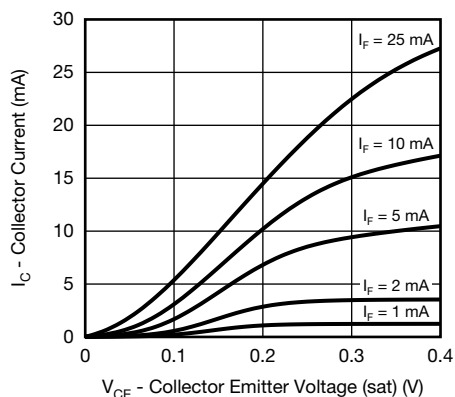


Fig. 6 - Collector Current vs. Collector Emitter Voltage (sat)

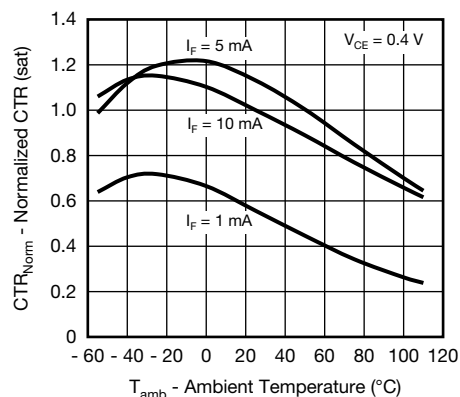


Fig. 9 - Normalized CTR (sat) vs. Ambient Temperature

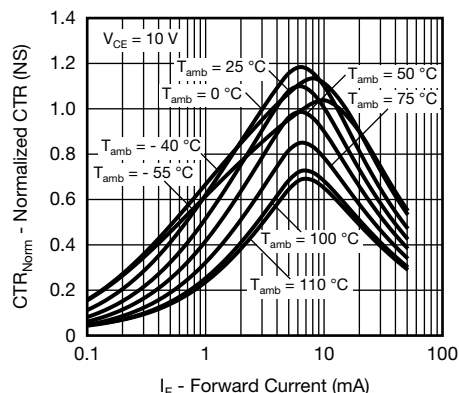


Fig. 10 - Normalized CTR (NS) vs. Forward Current

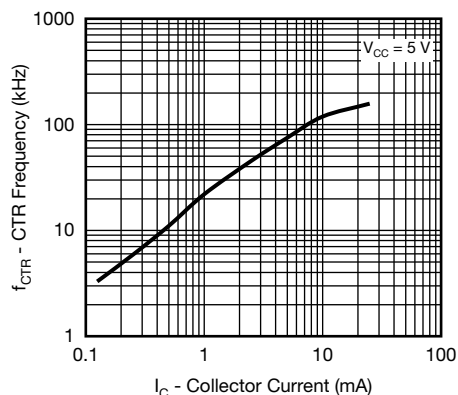


Fig. 13 - CTR Frequency vs. Collector Current

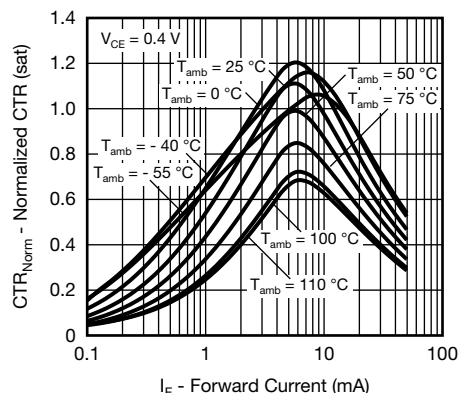


Fig. 11 - Normalized CTR (sat) vs. Forward Current

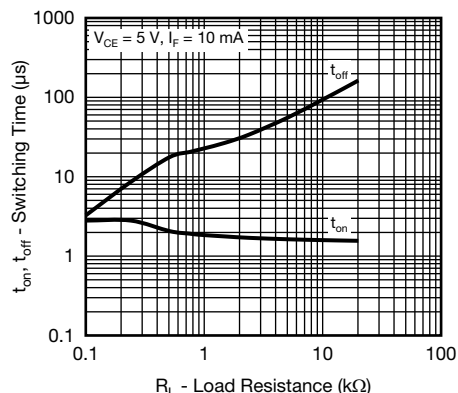


Fig. 14 - Switching Time vs. Load Resistance

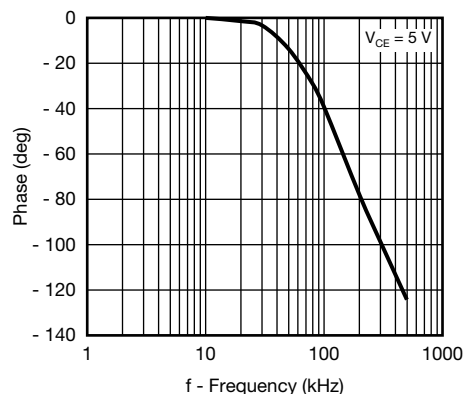
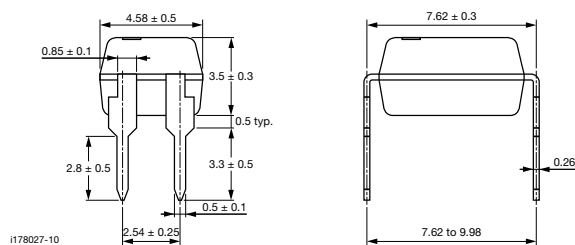
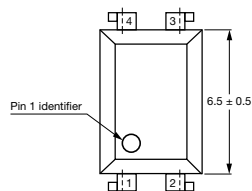


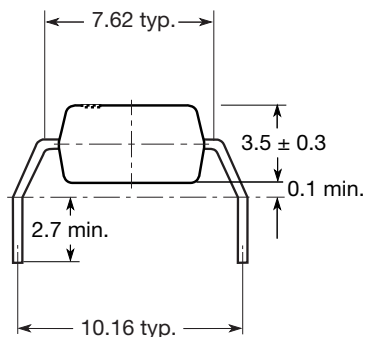
Fig. 12 - CTR Frequency vs. Phase Angle



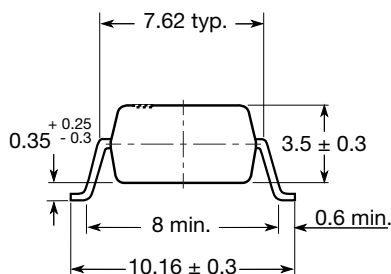
PACKAGE DIMENSIONS in millimeters



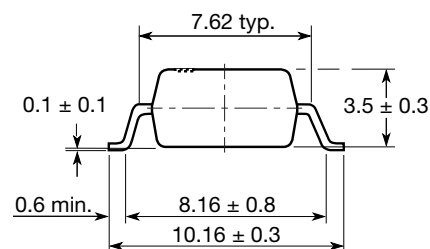
Option 6



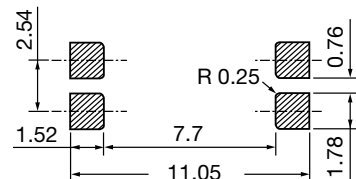
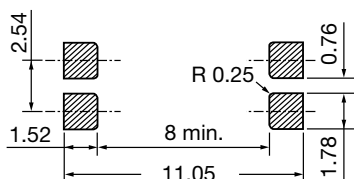
Option 7



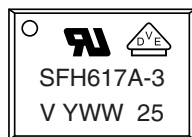
Option 9



20802-28



PACKAGE MARKING



Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.

SOLDER PROFILES

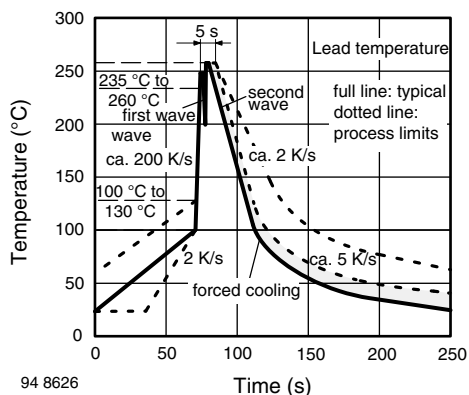


Fig. 15 - Wave Soldering Double Wave Profile According to J-STD-020 for DIP-8 Devices

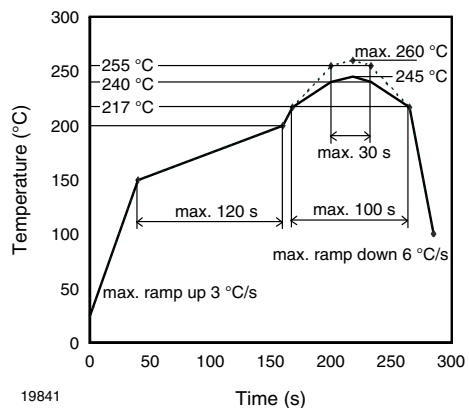


Fig. 16 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD-8 Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2

Floor life: unlimited

Conditions: $T_{amb} < 30\text{ °C}$, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.